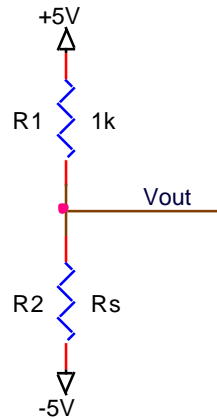
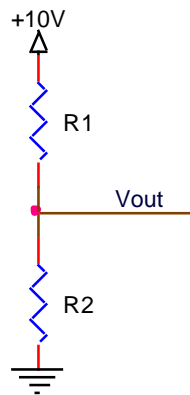


- 1) An unbuffered resistive sensor,  $R_s$ , is in the circuit shown below, where  $500 \Omega \leq R_s \leq 1.5 \text{ k}\Omega$ . What is  $V_{out}$  for the minimum, mid range and maximum resistance values of the sensor?

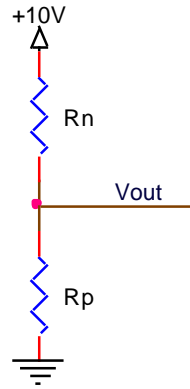


- 2) For the differential resistance sensor shown below, where  $R_1 = 1 \text{ k}\Omega + \Delta R$ ,  $R_2 = 1 \text{ k}\Omega - \Delta R$ , and  $0 \Omega \leq \Delta R \leq 100 \Omega$ , calculate the minimum and maximum  $V_{out}$ .



- 3) A rectangular resistive temperature sensor (5 mm long, 50  $\mu\text{m}$  wide and 1  $\mu\text{m}$  thick), where current flows through the length of the sensor, is made of a material with a resistivity of  $5 \times 10^{-6} \Omega\text{-cm}$  at  $0^\circ\text{C}$ , and a TCR of  $5 \times 10^{-3} (\text{ }^\circ\text{C})^{-1}$ . What is the approximate resistance at  $0^\circ\text{C}$  and  $100^\circ\text{C}$ ?
- 4) A certain metal strain gauge has a nominal resistance of 10  $\text{k}\Omega$  and a gauge factor of 1.8. If it experiences a 1% axial strain, what does the resistance become?
- 5) If the strain gauge in (4) experiences a -1% axial strain, what does the resistance become?

- 6) A polysilicon differential piezoresistive sensor is connected to a 10 V source as shown below, where  $R_n$  is a N-type piezoresistor and  $R_p$  is a P-type piezoresistor. With no strain on the piezoresistors,  $R_n = R_p = 1 \text{ k}\Omega$ . Calculate  $V_{out}$  for no strain. If  $R_n$  has a GF of -30 and  $R_p$  has a GF of +30, and both piezoresistors experience a 0.2% axial strain, calculate  $V_{out}$ .



- 7) If four piezoresistors from problem (6) are connected in a Wheatstone bridge configuration, as shown below, calculate  $V_{out} = V_2 - V_1$  for all resistors experiencing a 0.1% axial strain.

